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October 2014

# FDMS86163P

## P-Channel PowerTrench<sup>®</sup> MOSFET

-100 V, -50 A, 22 mΩ

### Features

- Max  $r_{DS(on)}$  = 22 mΩ at  $V_{GS} = -10$  V,  $I_D = -7.9$  A
- Max  $r_{DS(on)}$  = 30 mΩ at  $V_{GS} = -6$  V,  $I_D = -5.9$  A
- Very low RDS-on mid voltage P-channel silicon technology optimised for low Qg
- This product is optimised for fast switching applications as well as load switch applications
- 100% UIL tested
- RoHS Compliant

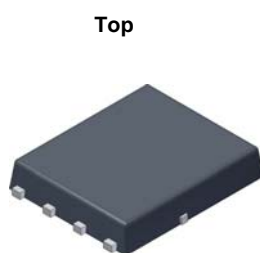


### General Description

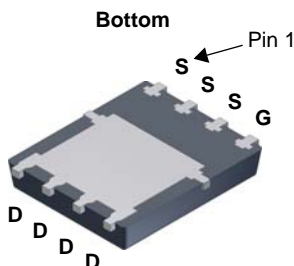
This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

### Applications

- Active Clamp Switch
- Load Switch

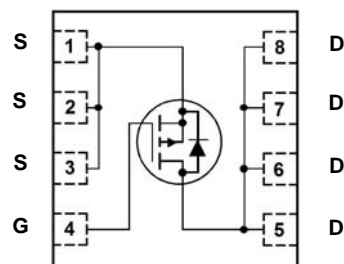


Top



Bottom

Power 56



### MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DS}$	Drain to Source Voltage	-100	V
$V_{GS}$	Gate to Source Voltage	$\pm 25$	V
$I_D$	Drain Current -Continuous $T_C = 25^\circ\text{C}$	-50	A
	-Continuous $T_A = 25^\circ\text{C}$ (Note 1a)	-7.9	
	-Pulsed (Note 4)	-100	
$E_{AS}$	Single Pulse Avalanche Energy (Note 3)	486	mJ
$P_D$	Power Dissipation $T_C = 25^\circ\text{C}$	104	W
	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1a)	2.5	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.2	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	50	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86163P	FDMS86163P	Power 56	13 "	12 mm	3000 units

**Electrical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Off Characteristics**

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = -250\ \mu\text{A}$ , $V_{GS} = 0\ \text{V}$	-100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$ , referenced to $25^\circ\text{C}$		-59		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = -80\ \text{V}$ , $V_{GS} = 0\ \text{V}$			-1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 25\ \text{V}$ , $V_{DS} = 0\ \text{V}$			$\pm 100$	nA

**On Characteristics**

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = -250\ \mu\text{A}$	-2	-2.8	-4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$ , referenced to $25^\circ\text{C}$		6.2		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = -10\ \text{V}$ , $I_D = -7.9\ \text{A}$		17.8	22	m $\Omega$
		$V_{GS} = -6\ \text{V}$ , $I_D = -5.9\ \text{A}$		21.3	30	
		$V_{GS} = -10\ \text{V}$ , $I_D = -7.9\ \text{A}$ , $T_J = 125^\circ\text{C}$		29	36	
$g_{FS}$	Forward Transconductance	$V_{DS} = -10\ \text{V}$ , $I_D = -7.9\ \text{A}$		29		S

**Dynamic Characteristics**

$C_{iss}$	Input Capacitance	$V_{DS} = -50\ \text{V}$ , $V_{GS} = 0\ \text{V}$ , $f = 1\ \text{MHz}$		3070	4085	pF
$C_{oss}$	Output Capacitance			501	670	pF
$C_{rss}$	Reverse Transfer Capacitance			21	35	pF
$R_g$	Gate Resistance		0.1	2.6	5.3	$\Omega$

**Switching Characteristics**

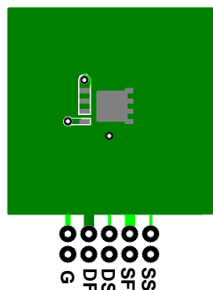
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -50\ \text{V}$ , $I_D = -7.9\ \text{A}$ , $V_{GS} = -10\ \text{V}$ , $R_{GEN} = 6\ \Omega$		17	30	ns
$t_r$	Rise Time			8.8	18	ns
$t_{d(off)}$	Turn-Off Delay Time			33	53	ns
$t_f$	Fall Time			6.9	14	ns
$Q_g$	Total Gate Charge	$V_{GS} = 0\ \text{V}$ to $-10\ \text{V}$	$V_{DD} = -50\ \text{V}$ , $I_D = -7.9\ \text{A}$	42	59	nC
$Q_g$	Total Gate Charge	$V_{GS} = 0\ \text{V}$ to $-6\ \text{V}$		26	37	nC
$Q_{gs}$	Gate to Source Charge			11.8		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			7.1		nC

**Drain-Source Diode Characteristics**

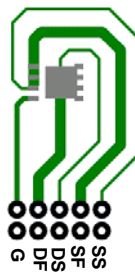
$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\ \text{V}$ , $I_S = -7.9\ \text{A}$ (Note 2)		-0.81	-1.3	V
		$V_{GS} = 0\ \text{V}$ , $I_S = -2\ \text{A}$ (Note 2)		-0.75	-1.2	
$t_{rr}$	Reverse Recovery Time	$I_F = -7.9\ \text{A}$ , $di/dt = 100\ \text{A}/\mu\text{s}$		63	102	ns
$Q_{rr}$	Reverse Recovery Charge			132	210	nC

**Notes:**

1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a)  $50^\circ\text{C}/\text{W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



b)  $125^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty cycle < 2.0%.

3. Starting  $T_J = 25^\circ\text{C}$ ; P-ch:  $L = 3\ \text{mH}$ ,  $I_{AS} = -18\ \text{A}$ ,  $V_{DD} = -100\ \text{V}$ ,  $V_{GS} = -10\ \text{V}$ . 100% test at  $L = 0.1\ \text{mH}$ ,  $I_{AS} = -58\ \text{A}$ .

4. Pulse  $I_d$  refers to Figure.11 Forward Bias Safe Operation Area.

# Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

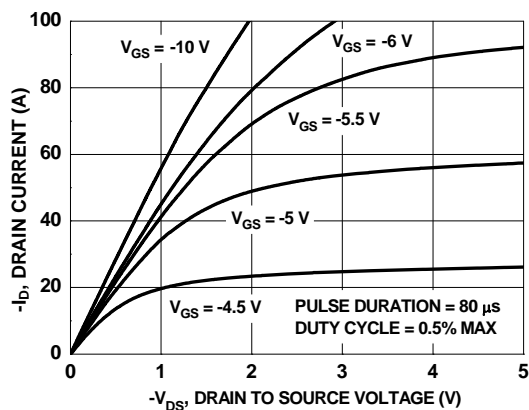


Figure 1. On Region Characteristics

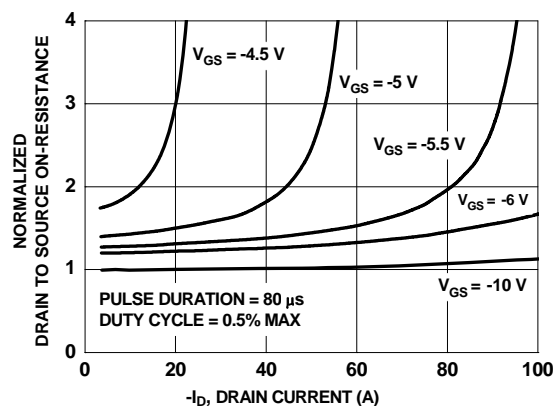


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

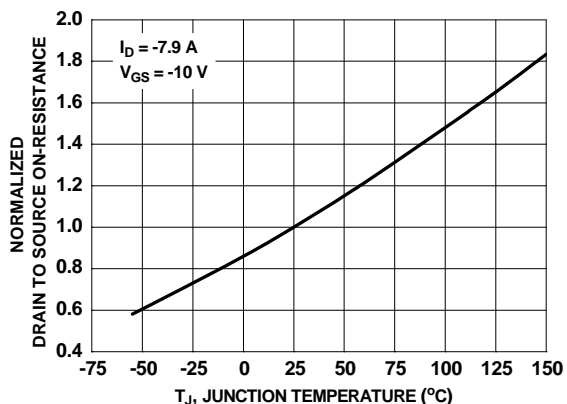


Figure 3. Normalized On Resistance vs Junction Temperature

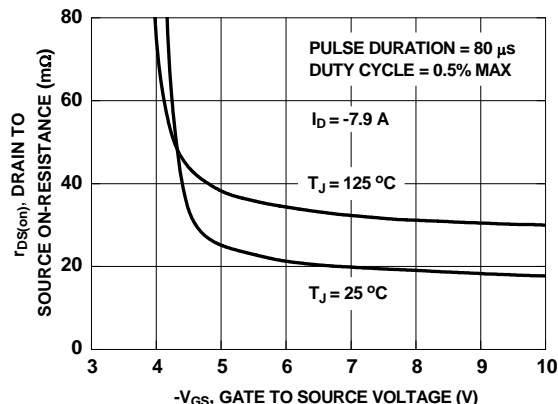


Figure 4. On-Resistance vs Gate to Source Voltage

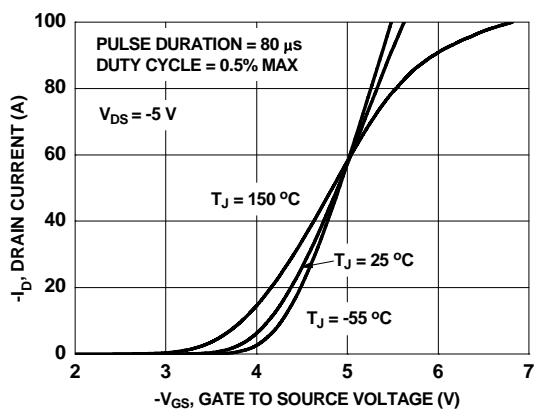


Figure 5. Transfer Characteristics

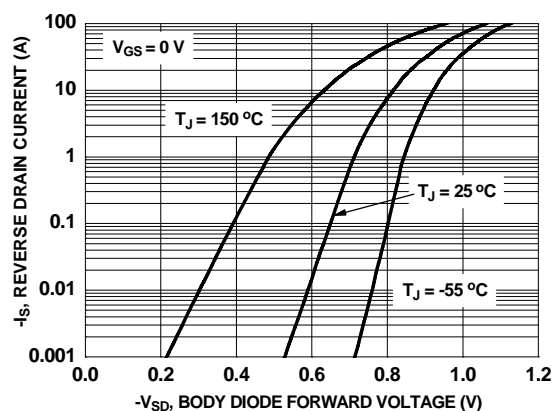


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

# Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

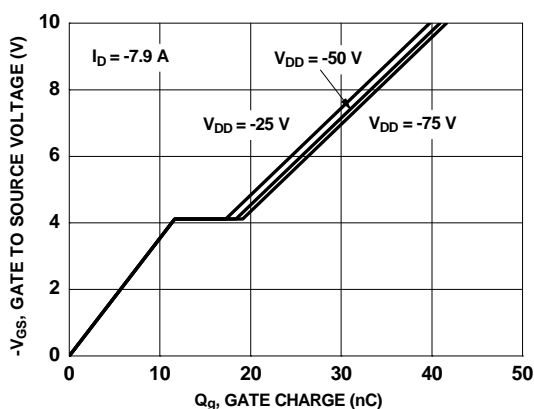


Figure 7. Gate Charge Characteristics

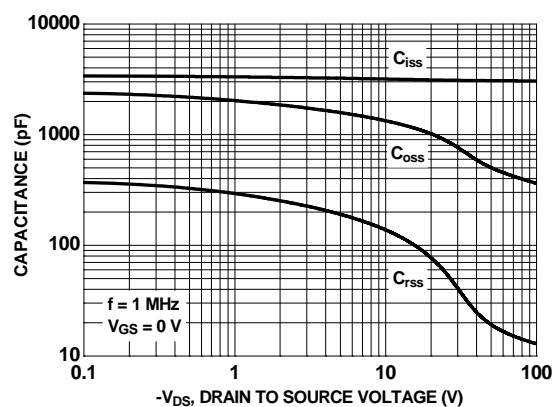


Figure 8. Capacitance vs Drain to Source Voltage

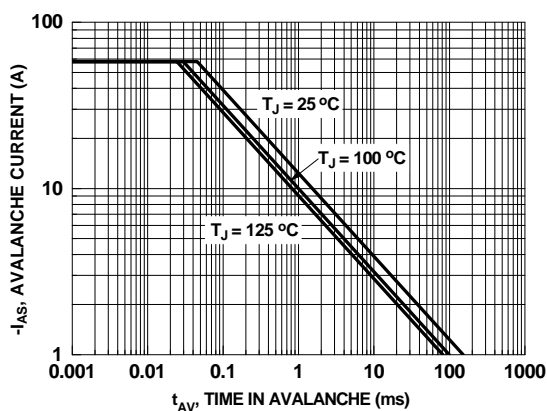


Figure 9. Unclamped Inductive Switching Capability

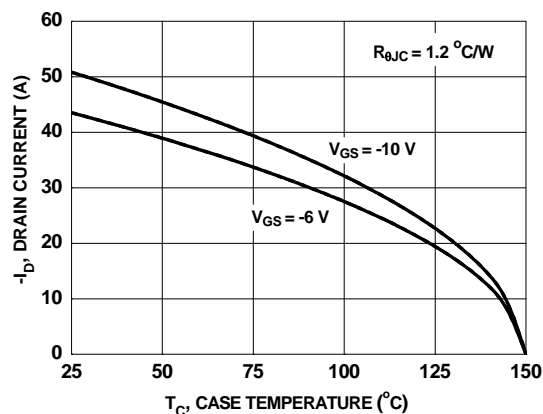


Figure 10. Maximum Continuous Drain Current vs Case Temperature

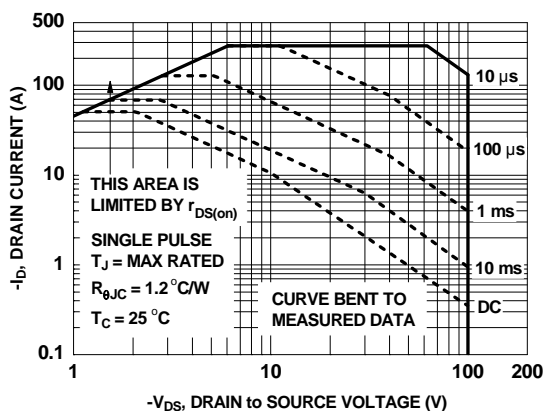


Figure 11. Forward Bias Safe Operating Area

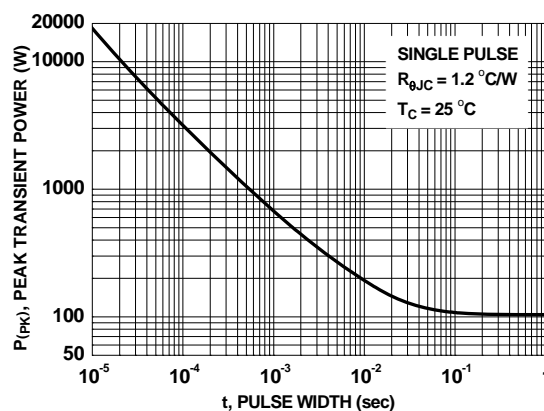


Figure 12. Single Pulse Maximum Power Dissipation

# Typical Characteristics $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise noted

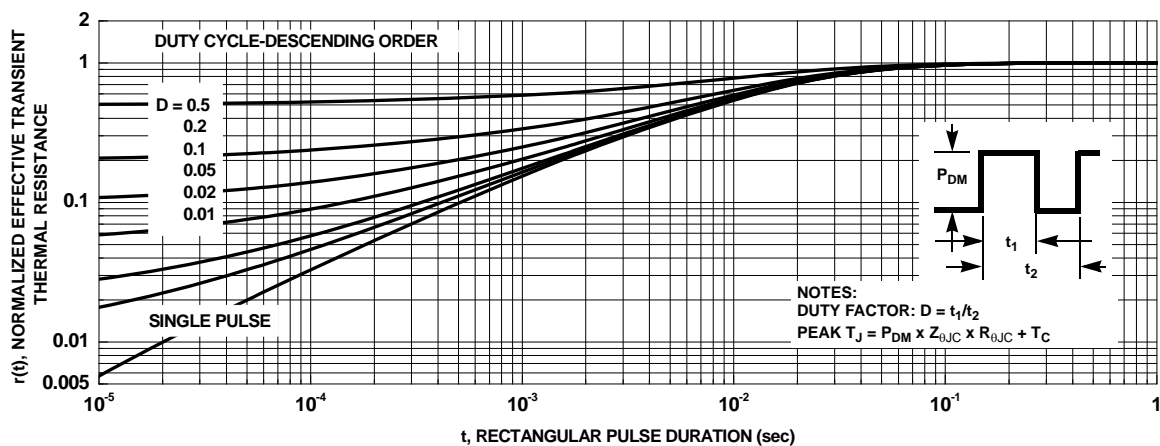
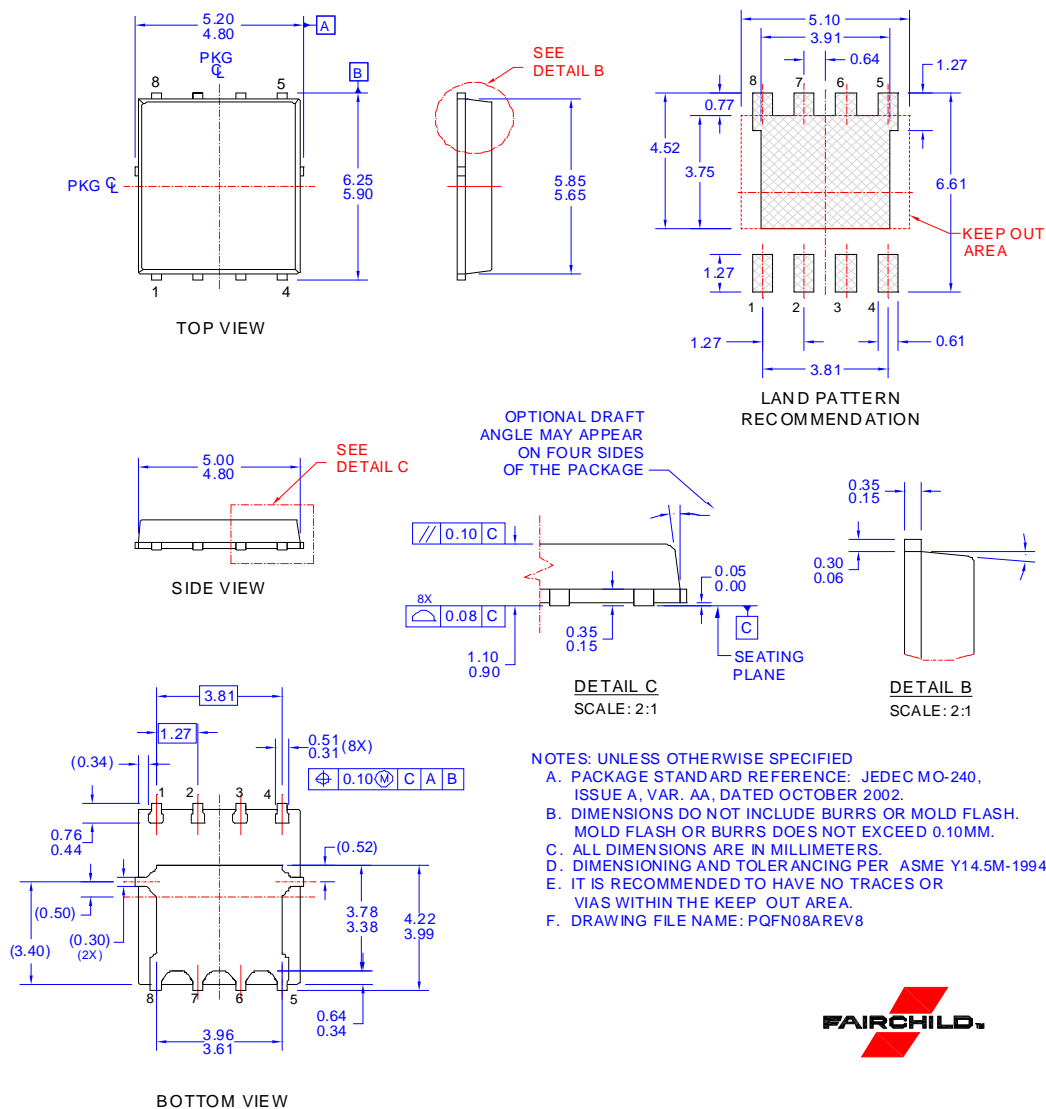


Figure 13. Junction-to-Case Transient Thermal Response Curve

## Dimensional Outline and Pad Layout



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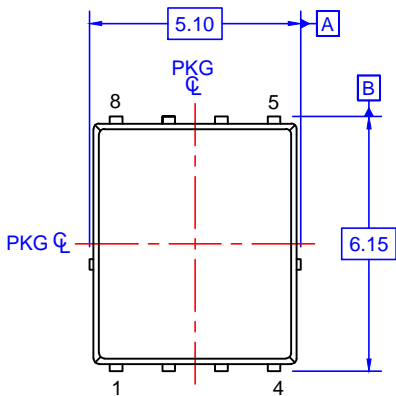
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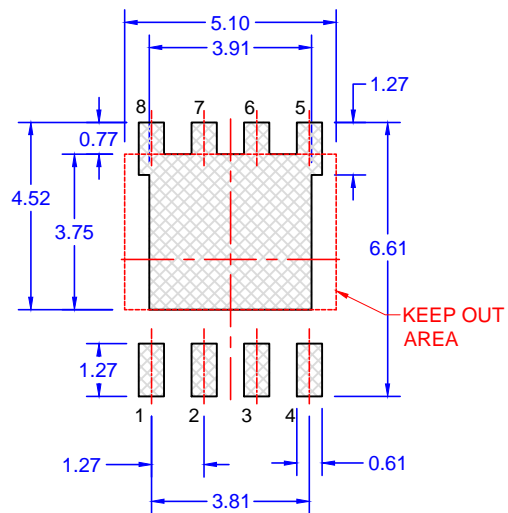
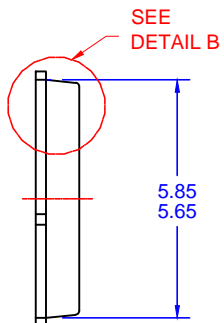
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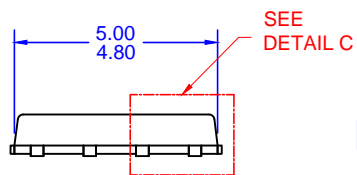
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ISSUE A



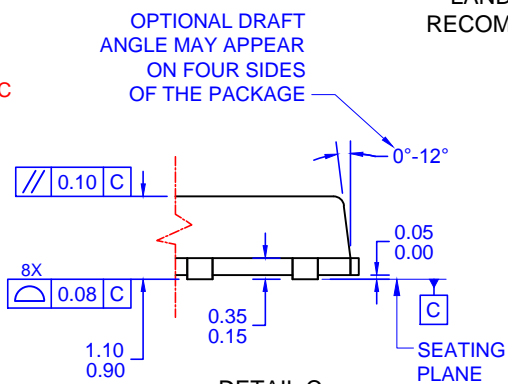
TOP VIEW



## LAND PATTERN RECOMMENDATION

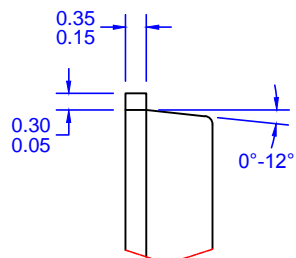


SIDE VIEW



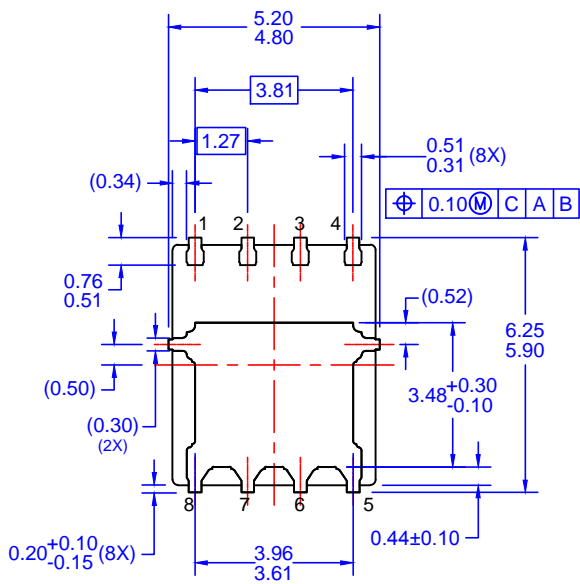
### DETAIL C

SCALE: 2:1



DETAIL B

SCALE: 2:1



BOTTOM VIEW

NOTES: UNLESS OTHERWISE SPECIFIED

- A. PACKAGE STANDARD REFERENCE: JEDEC MO-240, ISSUE A, VAR. AA.,
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- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2009.
- E. IT IS RECOMMENDED TO HAVE NO TRACES OR VIAS WITHIN THE KEEP OUT AREA.

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Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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